TF410



N-Channel JFET 40V, 50 to 130μA, 0.11mS, USFP

http://onsemi.com

Applications

· Impedance conversion, infrared sensor applications

Features

- · Ultrasmall package facilities miniaturization in end products: 1.0mm×0.6mm×0.27mm (max 0.3mm)
- Small IGSS: max -500pA (VGSS= -20V, VDS=0V)
- Small Ciss: typ. 0.7pF (VDS= 10V, VGS=0V, f=1MHz)
- · Halogen free compliance

Specifications

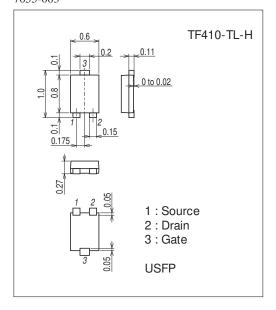
Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|------------------|------------|-------------|------|
| Drain-to-Source Voltage | VDSS | | 40 | V |
| Gate-to-Drain Voltage | V _{GDS} | | -40 | V |
| Gate Current | IG | | 10 | mA |
| Drain Current | ID | | 1 | mA |
| Allowable Power Dissipation | PD | | 30 | mW |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7055-003



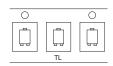
Product & Package Information

• Package : USFP

• JEITA, JEDEC : -

• Minimum Packing Quantity : 10,000 pcs./reel

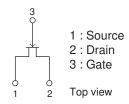
Packing Type: TL



07 N O O O

Marking

Electrical Connection

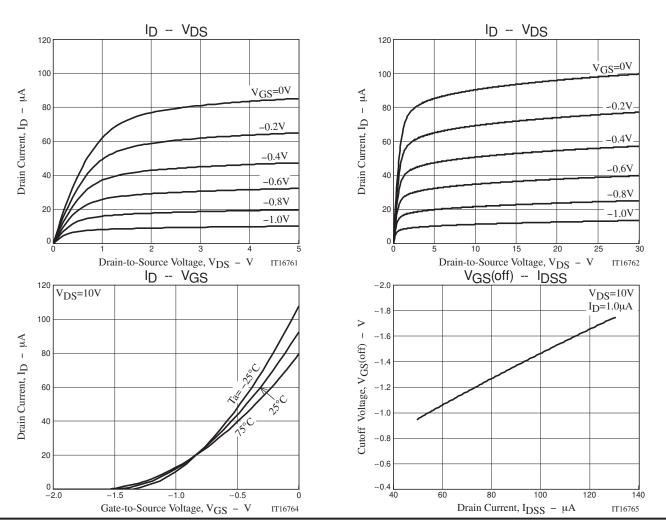


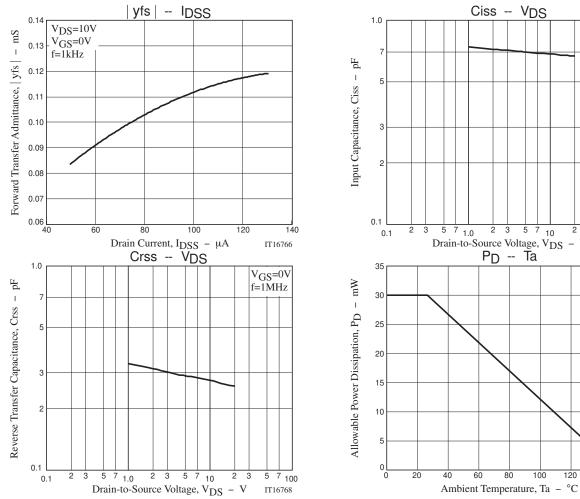
Electrical Characteristics at Ta=25°C

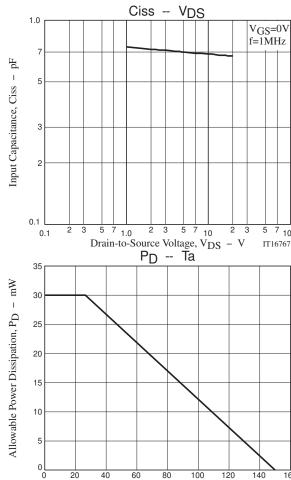
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---------------------------------|-----------------------|---|---------|------|------|-------|
| | Symbol | Conditions | min | typ | max | Offic |
| Gate-to-Drain Breakdown Voltage | V(BR)GDS | IG=-10μA, VDS=0V | -40 | | | V |
| Gate-to-Source Leakage Current | IGSS | V _{GS} =-20V, V _{DS} =0V | | | -500 | pA |
| Cutoff Voltage | V _{GS} (off) | V _{DS} =10V, I _D =1μA | | -1.4 | -4.0 | V |
| Drain Current | IDSS | V _{DS} =10V, V _{GS} =0V | 50 | | 130 | μΑ |
| Forward Transfer Admittance | yfs | V _{DS} =10V, V _{GS} =0V, f=1kHz | 0.05 | 0.11 | | mS |
| Input Capacitance | Ciss | VDS=10V, VGS=0V, f=1MHz | | 0.7 | | pF |
| Reverse Transfer Capacitance | Crss | VDS=10V, VGS=0V, I=1WIHZ | | 0.3 | | pF |

Ordering Information

| Device | Device Package | | memo | |
|------------|----------------|-----------------|--------------------------|--|
| TF410-TL-H | USFP | 10,000pcs./reel | Pb Free and Halogen Free | |







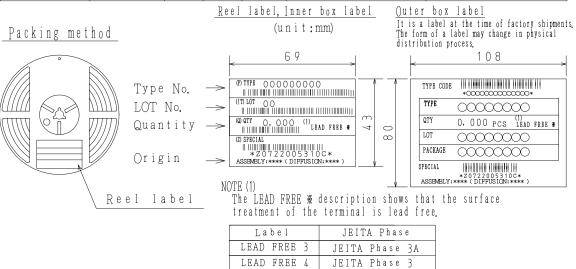
IT16778

Taping Specification

TF410-TL-H

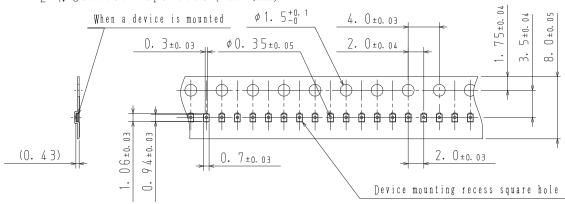
1. Packing Format

| Package Name | Carrier Tape | Maximum Number of devices contained (pcs) | | | Packing | ng format | | |
|--------------|--------------|--|-----------|-----------|--------------------------|--------------------------|--|--|
| | Туре | Reel | Inner box | Outer box | Inner $BOX(C-1)$ | Outer BOX (A-7) | | |
| USFP | USFP | 10,000 | 50,000 | 300,000 | 5 reels contained | 6 inner boxes contained | | |
| | | | | | Dimensions:mm (external) | Dimensions:mm (external) | | |
| | | | | | 183×72×185 | 440×195×210 | | |

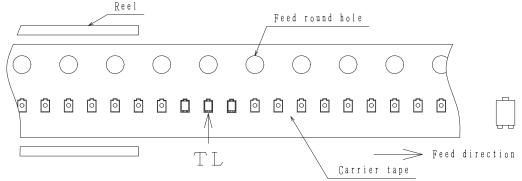


2. Taping configuration

2-1. Carrier tape size (unit:mm)



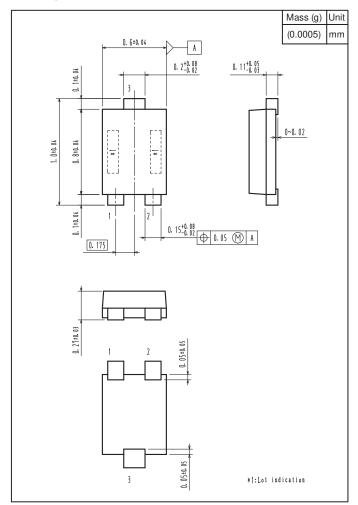
2-7. Device placement direction



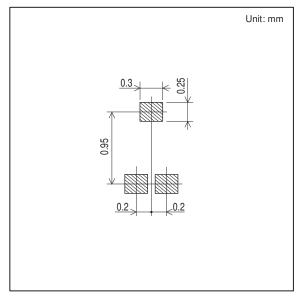
Those with one electrode terminal on the feed hole side·····TL

Outline Drawing

TF410-TL-H



Land Pattern Example



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